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6.5.2: The institution reviews its teaching learning process, structures & methodologies of operations and learning outcomes at periodic intervals through IQAC set up as per norms and recorded the incremental improvement in various activities

S. No.	Decision	Action Taken
1.	Accreditatio n Status	"A+" 3.33Granted by NAAC (Annexure-1)
2.	Add On Courses Initiated	All 10 Department initiated Add On Courses, student took benefit of this.  Link: <a href="https://ritengineering.education/pdf/C1/1.2.2%20-%20Number%20of%20Add%20on%20Certificate%20programs%20offered%20during%20the%20year.pdf">https://ritengineering.education/pdf/C1/1.2.2%20-%20Number%20of%20Add%20on%20Certificate%20programs%20offered%20during%20the%20year.pdf</a>
3.	Workshops/S eminars/Con ferences Conducted	Workshop :08 Seminar:04 Guest Lecture:02 Link: https://ritengineering.education/pdf/C3/3.2.2%20- %20Number%20of%20workshopsseminars%20conducted%20on%20Researc h%20Methodology,%20Intellectual%20Property%20Rights%20(IPR)%20and %20entrepreneurship.pdf
4.	Research / Patent/Public ation	Paper Published:26 Book Published:07 Link: https://ritengineering.education/pdf/C3/3.3.2%20- %20Number%20of%20research%20papers%20per%20teachers%20in%20the %20Journals%20notified%20on%20UGC%20website.pdf Patent:02 (Annexure-1)

Campus: NH-6, Chhatauna, MandirHasaud, Raipur (C.G.)- 492101 Ph.: 9522173000, 9522174000 Website: www.ritengineering.education E-mail: info@rit.edu.in, H.O: Near Bal Ashram, KutcheryChowk, Jail Road, Raipur- 492001 Chhattisgarh, India Ph.: 0771- 9522292121, 0771-4036053

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5.	Awareness/E xtension Activity	Activity: 12  Link: <a href="https://ritengineering.education/pdf/C3/3.4.3%20-">https://ritengineering.education/pdf/C3/3.4.3%20-</a>
		%20Number%20of%20extension%20and%20outreach%20programs%20con ducted%20by%20the%20institution%20through%20NSS-NCC- Red%20cross-YRC%20etc.pdf
6	IQAC Activities	https://ritengineering.education/pdf/iqac%20report%20summary%202022- 23.pdf

IQAC Coordinator

PRINCIPAL
RAIPUR INSTITUTE OF TECHNOLOGY
CHATAUNA, MANDIRHASAUD, RAIPUR (C.G.)

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(Annexure-1)

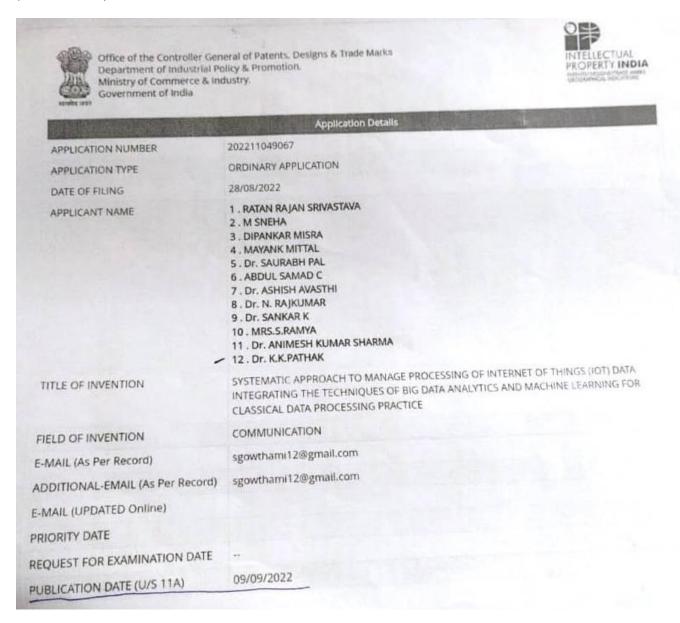


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#### (Annexure-2)



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(57) Abstract:

The present invention relates to the preparation of Prascodymism doped CulnS2 thin films by chemical deposition teclusique. Semiconducting films are grown in bath containing aqueous Solution of copper (II) chloride dihydrate, Indium (III) chloride, thiouren, TEA, aramonia (25%). The SEM Studies of Pr doped CulnS2 films show that at lower volume polyhedral shaped solution of copper (III) chloride dihydrate, Indium (III) chloride, thiouren, TEA, aramonia (25%). The SEM Studies of Pr doped CulnS2 films show that at lower volume polyhedral shaped solution of copper (III) chloride dihydrate, Indium (III) chloride, thiouren, TEA, aramonia (25%). The SEM Studies of Pr doped CulnS2 films shaped shaped speak appears between particle appears on the surface. Particle looks like accumulated wooken balls or cubic like grains in the XRD of prepared sample characteristic peaks of chalcopyrise place appears between (240–800) in all the films. Hall measurement shows that resistivity of Pr (omf) doped film is very high. The conductivity of all doped films is higher than undoped film. The Photoluminescence (240–800) in all the films. Hall measurement shows that resistivity of Pr (omf) doped film is very high. The conductivity of all doped films is higher than undoped film. The Photoluminescence (240–800) in all the films. Hall measurement shows that resistivity of Pr (omf) doped film is very high. The conductivity of all doped films is higher than undoped film. The Photoluminescence (240–800) in all the films. Hall measurement shows that resistivity of Pr (omf) doped film is very high. The conductivity of all doped films is higher than undoped film. The Photoluminescence (240–800) in all the films. Hall measurement shows that resistivity of Pr (omf) doped film is very high. The conductivity of all doped films is higher than undoped film. The Photoluminescence (240–800) in all the films. Hall measurement shows that resistivity of Pr (omf) doped film is higher than undoped film. The Photoluminescence (240–800) in al

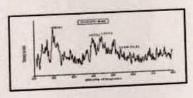


Figure 1

No. of Pages: 20 No. of Claims: 5

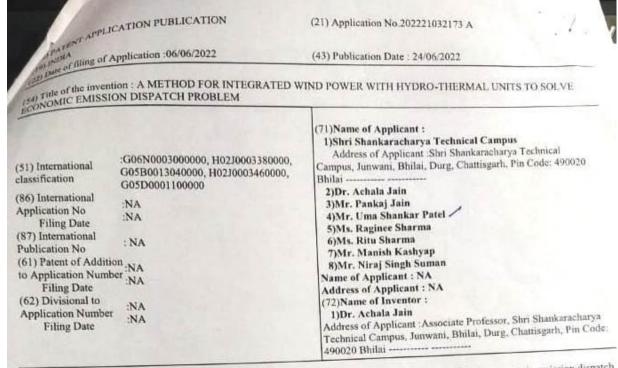
The Patent Office Journal No. 51/2022 Dated 23/12/2022

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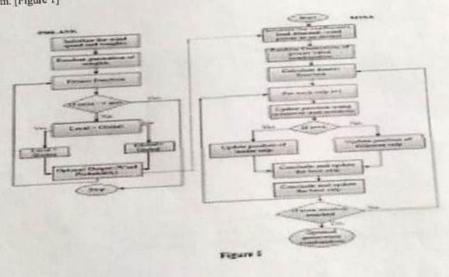
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(57) Abstract:

The present invention relates to a method for integrated wind power with hydro-thermal units to solve the economic emission dispatch problems. The method comprises a processing unit. The processing unit is configured to read machine language stored in the memory unit. The processing unit is configured to combine the modified salp swarm optimization algorithm (MSSA) and artificial intelligence (AI) technique aided with particle swarm optimization (PSO). The MSSA is configured to be utilized to optimize the combination of the thermal generators based on the wind power uncertainty and pumped storage units. The PSO-ANN is configured to be utilized to capture the uncertain events of wind power so the system is ensured the high utilization of wind power. The method determines complicated problems and appears to be a robust and efficient method for handling multi-objective optimization problems in power system. [Figure 1]



No. of Pages: 16 No. of Claims: 5

The Patent Office Journal No. 25/2022 Dated 24/06/2022